

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2	("6580474").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2006/09/30 18:27
L2	2	"6580474".pn. and storage adj capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 18:29
L3	4014	storage adj capacitor and ("tft" or thin adj film adj transistor) and gate adj electrode and channel	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 18:38
L4	1288	storage adj capacitor and ("tft" or thin adj film adj transistor) and gate adj electrode and channel and (low near3 concentration or low near3 impurity or "ldd") and wir\$3	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 19:24
L5	1	(pixel adj tft and channel adj formation and wiring adj line and low adj concentration adj impurity and gate adj electrode and storage adj capacitor and insulating).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 19:23
L6	52	storage adj capacitor and ("tft" or thin adj film adj transistor) and 257/57. ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 19:26
L7	583	storage adj capacitor and ("tft" or thin adj film adj transistor) and 257/59. ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 19:29
L8	108	storage adj capacitor and ("tft" or thin adj film adj transistor) and 257/66. ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 19:33
L9	4	storage adj capacitor and ("tft" or thin adj film adj transistor) and 257/288. ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 19:34
L10	158	storage adj capacitor and ("tft" or thin adj film adj transistor) and 257/347. ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 19:37
L11	126	storage adj capacitor and ("tft" or thin adj film adj transistor) and 257/350-351.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 19:54

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L12	40	storage adj capacitor and ("tft" or thin adj film adj transistor) and 257/291.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 19:56
L13	25	storage adj capacitor and ("tft" or thin adj film adj transistor) and 257/443.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 19:59
L14	0	storage adj capacitor and ("tft" or thin adj film adj transistor) and 257/229.202.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 19:59
L15	0	storage adj capacitor and ("tft" or thin adj film adj transistor) and 257/e29.202.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 19:59
L16	5	storage adj capacitor and ("tft" or thin adj film adj transistor) and 257/e29.273.ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2006/09/30 19:59